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July 2012

FXMHD103 — HDMI Voltage Translator

Features

- CEC, DDC, and HPD Level Shifting without a Direction Pin
- Host Port Voltage Supply (V_{CCA}): 1.6V 3.6V
- HDMI Port Voltage Supply (V_{CCC}): 4.8V 5.3V
- Long HDMI Cable Support with Integrated DDC (I²C) Edge Rate Accelerators
- Supports DDC (I²C) Clock Stretching
- Pin Out Tailored for PCB Trace Routing to HDMI Type D Connectors
- Back Drive Protection
- Non-Preferential Power-Up/Down Sequencing between VCCA and VCCC
- Operating Temperature Range: -40°C to 85°C
- ESD Protection:
 - 8kV HBM (per JESD22-A114)
 - 2kV CDM (per JESD22-C101)

Applications

- Smart Phones
- Multimedia Phones
- Digital Camcorders
- Digital Still Cameras
- Portable Game Consoles
- Notebooks
- MP3 Players
- PC and Consumer Electronics

Description

The FXMHD103 is a reduced-pin-count, low-power, High-Definition Multimedia Interface (HDMI), voltage translator for the Data Display Channel (DDC), Consumer Electronic Control (CEC), and Hot Plug Detect (HPD) control lines.

There are three non-inverting bi-directional voltage translation circuits for the DDC serial data (SDA)/clock (SCL) lines and CEC lines. Each line has a common power rail (V_{CCA}) on the host side from 1.6V to 3.6V. On the HDMI connector side, the SCL_C and SDA_C pins each have an internal 1.75K Ω pull-up connected to the HDMI 5V rail, V_{CCC}. The SCL and SDA pins exceed the HDMI specification for driving up to 800pF loads. The CEC_C pin has an internal 27K Ω pull-up to an internal 3.3V supply (V_{REG}).

The HPD_C path is uni-directional. The direction is from the HDMI connector port to the host port. HPD_H references V_{CCA} , and HPD_C references V_{CCC} . HPD_C offers hysteresis to avoid false detection due to bouncing while inserting the HDMI plug.

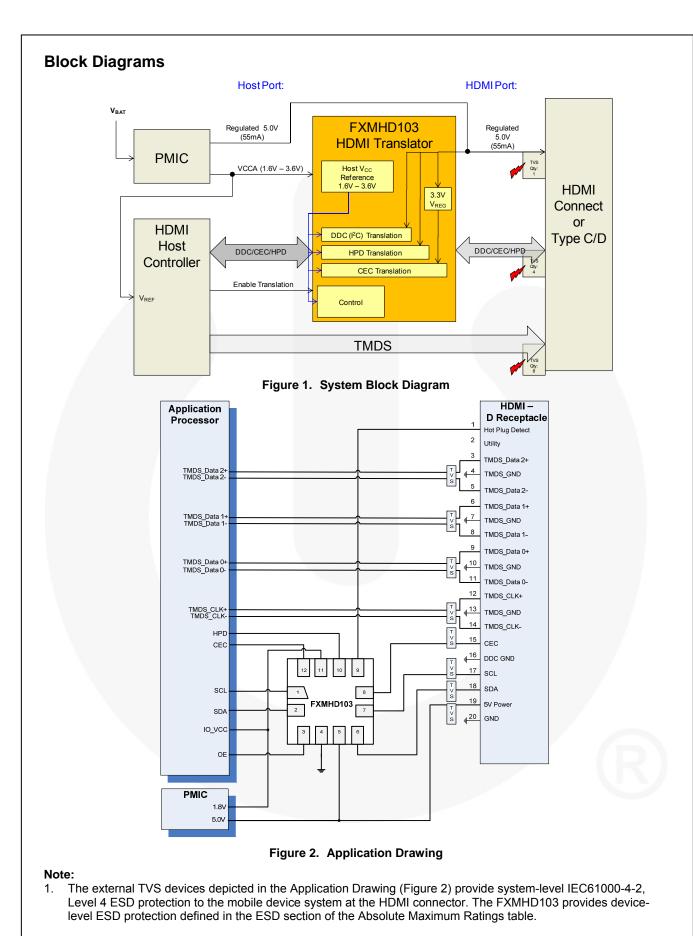
The FXMHD103 device can be powered down if the OE pin is LOW. If OE is HIGH, the HPD path is enabled. If an HDMI sink asserts the HPD_C pin HIGH, the DDC and CEC paths are enabled. OE references V_{CCA} .

Back drive protection is provided on pins facing the HDMI connector.

0.40										
Part	Part Number Top Mark		Operating Temperature Range	Package	Packing Method					
FXMH	HD103UMX	BZ	-40°C to 85°C	12-Terminal, Quad µMLP, 1.8mm x 1.8mm Package	5000 Units on Tape and Reel					

Ordering Information







VCCC

SCL C

SDA_C

7

6

5

 C_{VCCC}

0.1µF

Block Diagrams (Continued) VCCA 11 _C_{VCCA} 0.1μF 3.3V V_{REG} (Internal) OE 3 OE Internal 470ΚΩ V_{CCA} V_{ccc} SCL H 10KΩ 1.75KΩ NpassGate With Edge Rate Accelerator 1 OE_internal Vccc VccA ≤ 1.75ΚΩ SDA H 10KΩ NpassGate With Edge Rate 2 Accelerator

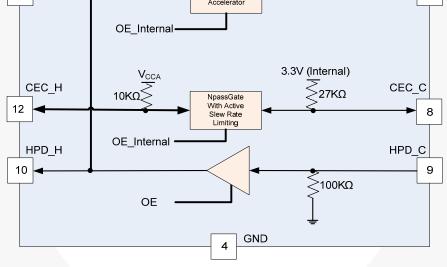


Figure 3. Circuit Block Diagram

 Table 1.
 Truth Table (V_{CCA} & V_{CCC} Valid)

OE	HPD_C	OE Internal	VREG	HPD_H	SCL_C	SDA_C	CEC_C
LOW	Don't Care	LOW	Disabled	3-State	3-State	3-State	3-State
HIGH	LOW	LOW	Disabled	Enabled	3-State ⁽²⁾	3-State ⁽²⁾	3-State ⁽²⁾
HIGH	HIGH	HIGH	Enabled	Enabled	Enabled	Enabled	Enabled

Note:

2. SCL_C and SDA_C internally pulled up to V_{CCC}. CEC_C is 0V because V_{REG} is disabled. This is required for HDMI compliance testing. The VOUT_{DIS} parameter captures this requirement.

Pin Configuration CEC_H н_очн нрр_с VCCA 12 9 11 10 8 1 CEC_C SCL_H 2 7 SCL_C SDA_H 3 5 6 4 SDA_C VCCC GND Ю



Pin Definitions

Pin #	Signal Name	Description
1	SCL_H	Host-side (DDC) SCL bi-directional I ² C pin; referenced to VCCA.
2	SDA_H	Host-side (DDC) SDA bi-directional I ² C pin; referenced to VCCA.
3	OE	Output enable: LOW=DDC, CEC, & HPD paths disabled; HIGH=DDC, CEC, & HPD paths enabled.
4	GND	Device GND
5	VCCC	HDMI port supply: 5V V _{CC} reference for HPD_C, SCL_C, SDA_C, and V _{REG} input.
6	SDA_C	Connector-side (DDC) SDA bi-directional I ² C pin; referenced to VCCC.
7	SCL_C	Connector-side (DDC) SCL bi-directional I ² C pin; referenced to VCCC.
8	CEC_C	Connector-side (CEC) bi-directional pin; referenced to internal 3.3V voltage regulator (V_{REG}). RPU decoupled from "3.3V Internal" if OE=LOW.
9	HPD_C	Connector-side HPD, input for the "hot plug" detect.
10	HPD_H	Host-side HPD; output for the hot plug detect. This pin references VCCA and indicates to the HDMI controller (HDMI source) when there is an HDMI sink connected to the FXMHD103.
11	VCCA	Host-side power supply, 1.6V – 3.6V.
12	CEC_H	Host-side CEC, bi-directional pin; referenced to VCCA. RPU decoupled from VCCA if OE=LOW.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Condition		Min.	Max.	Unit
Vcc	Supply Voltage Range	VCCA, VCCC		-0.5	6.5	V
V _{IN} ⁽³⁾		SCL_H, SDA_H, CEC_H	, OE	-0.5	6.5	V
VIN	Input Voltage Range	SCL_C, SDA_C, CEC_C	, HPD_C	-0.5	6.5	
V0 ⁽³⁾	Output Valtage	SCL_H, SDA_H, CEC_H	, HPD_H	-0.5	6.5	
_	Output Voltage	SCL_C, SDA_C, CEC_C		-0.5	6.5	V
I _{IK}	Input Clamp Current	V _{IN} < 0V			-50	mA
Іок	Output Clamp Current	V ₀ < 0V			-50	mA
TJ	Junction Temperature			-40	+150	°C
T _{STG}	Storage Temperature Range			-65	+150	°C
		Human Body Model, JESD22-A114-B	All Pins		8	
ESD	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101	All Pins		2	kV
			Air Gap		16	
		IEC 61000-4-2	Contact		9	

Note:

3. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings. Unless otherwise noted, values are across the recommended operating free-air temperature range.

Symbol	Parameter		Condition	Min.	Max.	Unit	
V_{CCA}	Supply Voltage	VCCA		1.6	3.6	V	
V _{ccc}	Supply Voltage	VCCC		4.8	5.3	V	
	Input Voltages	Host Port	SCL_H, SDA_H, CEC_H	0	V _{CCA}		
			OE	0	V _{CCA}		
VIN		Connector Port	SCL_C, SDA_C	0	V _{CCC}	V	
			CEC_C	0	3.3V (Internal)		
			HPD_C	0	V _{CCC}		
TA	Ambient Temperature			-40	+85	°C	
TJ	Junction Temperature	Junction Temperature			+125	°C	

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with fourlayer 2s2p boards in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature T_J (maximum) at a given ambient temperature.

Symbol	Parameter	Тур.	Unit
Θ_{JA}	Junction-to-Ambient Thermal Resistance	320	°C/W

DC Electrical Characteristics (I_{cc})

Unless otherwise specified, T_A =-40 to 85°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
I _{CCPD1}	Power Down 1	V_{CCA} =0V, or V_{CCC} =0V, All Other Pins=Don't Care			1	μA
I _{CCPD2}	Power Down 2	OE=LOW, V _{CCA} and V _{CCC} Valid, All Other Pins=Don't Care			1	μA
I _{CCHPD}	Active HPD Only	OE=HIGH, V _{CCA} and V _{CCC} Valid, SCL_H, SDA_H and CEC_H=HIGH, HPD_C=0V			1.5	μA
I _{CCA}	Active HDMI Link	V_{CCA} and V_{CCC} Valid, SCL_H, SDA_H and CEC_H=HIGH, HPD_C=V_{\text{CCC}}, OE=HIGH			5	μA
Iccc		V_{CCA} and V_{CCC} Valid, SCL_H, SDA_H and CEC_H=HIGH, HPD_C=V_{\text{CCC}}, OE=HIGH			5	μA

Back Drive Current

Unless otherwise specified, T_A =-40 to 85°C.

Symbol	Parameter	Condition	V_{CCA}	V _{ccc}	Тур.	Max.	Unit
Iback _{CEC}	Current Through CEC_C	CEC_C=0V - 5V	0V	0V	0.1	1.8	μA
Iback _{DDC}	Current Through SDA_C and SCL_C	SDA_C and SCL_C=0V – 5V	0V	0V	0.1	5.0	μA
Iback _{VCCC}	Current Through VCCC	$V_{CCC}=0V-5V$	0V	NA	0.1	5.0	μA
Iback _{HPD}	Current Through HPD_C	HPD_C=0V – 5V	0V	0V	0.1	5.0	μA

Voltage Level Shifter: SCL, SDA Lines (Host/Connector Ports)

Unless otherwise specified, T_A =-40 to 85°C.

Symbol	Parameter	Condition	V _{CCA}	Min.	Тур.	Max.	Unit	
V	High Level input Voltage	Host Side	1.6V to 3.6V	V _{CCA} - 0.4			v	
V _{IH}	nigh Level linput voltage	Connector Side	1.6V to 3.6V	V _{CCC} - 0.4				
		Host Side	<2V			0.2 x V _{CCA}		
VIL	Low Level Input Voltage	Host Side	>2V			0.4	V	
		Connector Side	1.6V to 3.6V			0.4		
V _{OH}		Host Side: I _{OH} =-10µA	1.6V to 3.6V	V _{CCA} x 0.8			v	
	High Level Output Voltage	Connector Side: I _{OH} =-10µA	1.6V to 3.6V	V _{CCC} - 0.3			v	
V _{OL1}		I _{OL} =3mA, V _{IL} =0V; Both Directions	1.6V to 3.6V			0.05	V	
V _{OL2}	Low Level Output Voltage	I _{OL} =3mA, V _{IL} =0.25V; Both Directions	1.6V to 3.6V			0.30	V	
V _{OL3}		I _{OL} =3mA, V _{IL} =0.3V; Both Directions	1.6V to 3.6V			0.35	v	
V _{OL4}		I _{OL} =3mA, V _{IL} =0.4V; Both Directions	1.6V to 3.6V			0.45	v	
V _{OL5}		I _{OL} =3mA, V _{IL} =0.6V C→ H Direction Only	1.6V to 3.6V			0.65	v	
	lateral Dall or	SCL_H, Internal Pull-up Connected to SDA_H, VCCA Rail			10.00		kΩ	
RPU	Internal Pull-up	SCL_C, Internal Pull-up Connected to SDA_C, VCCC			1.75			
Ipullupac	Transient Boosted Pull-up Current (Edge Rate Accelerator)	SCL_C, Internal Pull-up Connected to SDA_C, VCCC			15		mA	
	Host Port	V_{CCA} =0V, V _I or V _O =0 to 3.6V	0V			±5		
I _{OFF}	Connector Port	V_{CCC} =0V, V _I or V _O =0 to 5.3V	0V to 3.6V			±5	μA	
1	Connector Port	Vo=VCCO or GND	1.6V to 3.6V			±5		
loz	Host Port	V _I =VCCI or GND	1.6V to 3.6V			±5	μA	

Voltage Level Shifter: CEC Lines (Host/Connector Ports)

Unless otherwise specified, T_A =-40 to 85°C.

Symbol	Parameter	Condition	V _{CCA}	Min.	Тур.	Max.	Unit	
V _{IH}	High Level input Voltage	Host Side	1.6V to 3.6V	V _{CCA} - 0.4		V _{CCA}	V	
		Host Side	<2V			0.2 x V _{CCA}		
VIL	Low Level Input Voltage	Host Side	>2V			0.4	V	
		Connector Side	1.6V to 3.6V			0.6		
V _{OH}	High Level Output Voltage	Host Side, I _{OH} =-10µA	1.6V – 3.6V	V _{CCA} x 0.8			V	
V _{OH}	High Level Output Voltage	Connector Side, I _{OH} =-10µA	1.6V – 3.6V	2.75	3.10		V	
V_{OL1}		I _{OL} =3mA, V _{IL} =0V	1.6V to 3.6V			0.05	V	
V_{OL2}		I _{OL} =3mA, V _{IL} =0.25V	1.6V to 3.6V			0.30	V	
V_{OL3}	Low Level Output Voltage Host & Connector Sides	I _{OL} =3mA, V _{IL} =0.3V	1.6V to 3.6V			0.35	V	
V _{OL4}		I _{OL} =3mA, V _{IL} =0.4V	1.6V to 3.6V			0.45	V	
V _{OL5}		I _{OL} =3mA, V _{IL} =0.6V	1.6V to 3.6V			0.65	V	
VOUT _{DIS}	Output Voltage when Disabled	CEC_C: HPD_C=LOW, OE=HIGH, V _{CCC} =4.8V – 5.3V	1.6V to 3.6V			0.3	V	
		CEC_H, Internal Pull-up Connected to VCCA Rail			10			
R _{PU}	Internal Pull-up	CEC_C, Internal Pull-up Connected to Internal 3.3V Rail			27		kΩ	
	H Port	V_{CCA} =0V, V _I or V _O =0 to 3.6V	0V			±5.0		
I _{OFF}	C Port	V_{CCC} =0V, V _I or V _O =0 to 5.3V	0V to 3.6V			±1.8	μA	
1	C Port	V _O =VCCO or GND	1.6V to 3.6V			±5.0		
l _{oz}	H Port	VI=VCCI or GND	1.6V to 3.6V			±5.0	μA	

Voltage Level Shifter: HPD Lines (Host/Connector Ports)

 T_A =-40 to 85°C unless otherwise specified.

Symbol	Parameter	Condition	V _{CCA}	Min.	Тур.	Max.	Unit
V _{IH}	High Level Input Voltage		1.6V to 3.6V	2			V
VIL	Low Level Input Voltage		1.6V to 3.6V			0.8	V
V _{OH}	High Level Output Voltage	I _{OH} =-3mA	1.6V to 3.6V	0.7 x V _{CCA}		1	V
V _{OL}	Low Level Output Voltage	I _{OL} =3mA	1.6V to 3.6V			0.3	V
V_{HYS}	HPD_C (V _{T+} - V _{T-})		1.6V to 3.6V		200		mV
R _{PD}	Internal Pull-Down	HPD_C, Internal Pull-down Connected to Ground, VCCA and VCCC Powered up			100		KΩ
I _{OFF}	Host Port	Vo=Vcco or GND	0V			±5	μA
I _{oz}	Host Port	V _I =V _{CCI} or GND	3.6V			±5	μA

AC Electrical Characteristics⁽⁴⁾

Unless otherwise specified, T_A =-40 to 85°C. Typical values T_A = 25°C.

Voltage Level Shifter: SCL, SDA Lines (Host and Connector Ports); V_{CCA}=1.8V

Symbol	Parameter	Pins	Condition	Min.	Тур.	Max.	Unit
4		H to C			100		
t _{PHL}	Propagation Delay	C to H	DDC Channels Enabled		5		20
4		H to C			25		ns
t _{PLH}		C to H			5		
+	H Port Fall Time	H Port	DDC Channels Enabled 70% -30%		2		20
t _f	C Port Fall time	C Port	DDC Channels Enabled 70% -30%		80		ns
+	H Port Rise Time	H Port	DDC Channels Enabled 30% -70%		2		20
tr	C Port Rise Time	C Port	DDC Channels Enabled 30% -70%		50		ns
f _{MAX}	Maximum Switching Frequency		DDC Channels Enabled	400			kHZ

Voltage Level Shifter: CEC Line (Host and Connector Ports); V_{CCA}=1.8V

Symbol	Parameter	Pins	Condition	Min.	Тур.	Max.	Unit
t =		H to C			100		20
t _{PHL}	Propagation Delay	C to H	CEC Channels Enabled		5		ns
+		H to C			25		ns
t _{PLH}		C to H			5		
•	H Port Fall Time	H Port	CEC Channels Enabled 90% - 10%		10	50000	20
t _f	C Port Fall time	C Port			200	50000	ns
	H Port Rise Time	H Port			5	400	ns
t _r	C Port Rise Time	C Port	CEC Channels Enabled 10% - 90%		0.2	250	μs

Voltage Level Shifter: HPD Line (Host and Connector Ports); V_{CCA}=1.8V

Symbol	Parameter	Pins	Condition	Min.	Тур.	Max.	Unit
t _{PHL}	Dranagation Dalay	C to H			10		-
t _{PLH}	Propagation Delay	C to H	HPD Channel Enabled		5		ns
t _f	H Port Fall Time	H Port	HPD Channel Enabled 90% - 10%		1		ns
tr	H Port Rise Time	H Port	HPD Channel Enabled 10% - 90%		3	1	ns

I/O Capacitance

 T_A = 25°C unless otherwise specified.

Symbol	Parameter	Condition	$V_{CCA \&} V_{CCC}$	Min.	Тур.	Max.	Unit
Cı	Control Inputs		0V		2		pF
	DDC & CEC on Host Port		0V		5		pF
C _{IO}	DDC on Connector Port	LCR: V _{bias} =2.5V; AC Input=3.5V _{pp} ; f=100kHZ	0V		10	16.5	pF
	CEC on Connector Port	LCR: V _{bias} =1.65V; AC Input=2.5V _{pp} ; f=100kHZ	0V		10	16.5	pF

Note:

4. AC Characteristics are guaranteed by Design and Characterization, not production tested.

AC Parameter Measurement Information^(5,6,7,8,9)

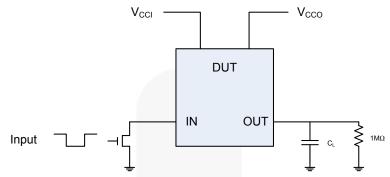


Figure 5. Device Under Test Setup

Table 2. AC Load

Symbol	Parameter	Condition	V _{CCA}	Min.	Тур.	Max.	Unit
	Bus Load Capacitance (Connector-Side)	CEC	1.6V to 3.6V			1300	
CL	Bus Load Capacitance (Connector-Side)	DDC & HPD	1.6V to 3.6V			800	pF
	Bus Load Capacitance (Host-Side)	All Pins	1.6V to 3.6V			15	

Notes:

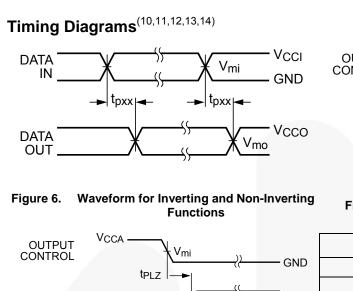
5. R_T termination resistance should be equal to Z_{OUT} of the pulse generator.

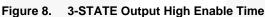
6. C_L includes probe and jig capacitance.

7. All input pulses supplied by generators have the following characteristics: PRR \leq 10MHz, Z₀=50 Ω , slew rate \geq 1V/ns.

8. The outputs are measured one at a time, with one transition per measurement.

9. t_{PLH} and t_{PHL} are the same as t_{PD} .





Vol

DATA OUT

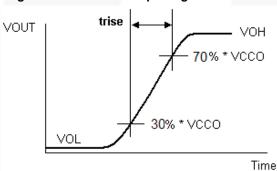
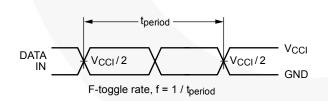


Figure 9. Active Output Rise Time





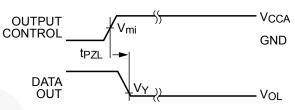
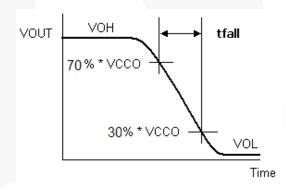


Figure 7. 3-STATE Output Low Enable Time

Symbol	V _{cc}
V _{mi}	V _{CCI} / 2
V _{mo}	V _{CCO} / 2
V _X	0.5 x V _{CCO}
V _Y	0.1 x V _{CCO}



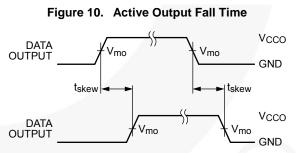




Figure 12. Output Skew Time

Notes:

- 10. Input $t_R=t_F=2.0ns$, 10% to 90% at $V_{IN}=1.65V$ to 1.95V; Input $t_R=t_F=2.0ns$, 10% to 90% at $V_{IN}=2.3$ to 2.7V; Input $t_R=t_F=2.5ns$, 10% to 90%, at $V_{IN}=3.0V$ to 3.6V only; Input $t_R=t_F=2.5ns$, 10% to 90%, at $V_{IN}=4.5V$ to 5.5 only.
- 11. $V_{CCI}=V_{CCA}$ for control pin OE or $V_{mi}=(V_{CCA} / 2)$.
- 12. DDC Rise Times 30% 70%, CEC & HPD Rise Times 10% 90%
- 13. DDC Fall Times 30% 70%, CEC & HPD Fall Times 10% 90%
- 14. V_{CCI} is the V_{CC} associated with the input side. V_{CCO} is the V_{CC} associated with the output side.

Application Information

Power Down

The FXMHD103 can be powered down if either V_{CCA} or V_{CCC} equals 0V, or if OE is LOW.

"Hot Plug" Detect Operation

After VCCA and VCCC have powered up to valid levels, and OE enabled (HIGH) the HPD path is enabled. The internal 3.3V voltage regulator and the CEC & DDC blocks are disabled due to the internal weak pull-down resistor (100k Ω to GND) on HPD C. When the HDMI sink recognizes a valid 5V signal on the HDMI connector, to inform the HDMI source there is a valid HDMI sink connected to the HDMI connector; the sink typically ties the HPD_C signal to the HDMI 5V supply through a $1K\Omega$ resistor. A HIGH on HPD C, in turn, enables the internal voltage regulator, as well as the DDC & CEC paths. The HDMI link is active between the HDMI source and the HDMI sink.

When HPD C is LOW, the respective resistor pullups (RPUs) on the host and connector sides of the DDC paths remain coupled to their respective voltage references. Likewise, when HPD C is LOW, the RPUs on the host and connector sides of the CEC path remain coupled to their respective voltage references. Since HPD C disables V_{REG} and V_{REG} is the CEC C voltage reference, CEC C is held to 0V by a weak (50nA) current source when HPD_C is LOW. This is captured by the VOUT_{DIS} parameter.

VccA

Backdrive Protection

Backdrive-current protection is available on all FXMHD103 signals interfacing with the HDMI connector, including VCCC, SCL C, SDA C, CEC C, and HPD C. If the FXMHD103 is powered down, $V_{CCA}=0V$ or $V_{CCC}=0V$ and the HDMI sink forces 0V - 5V onto any of the HDMI connector-facing pins (VCCC, SCL_C, SDA_C, CEC C & HPD C). The maximum current flow from the FXMHD103 is only 5µA, with the exception of 1.8µA (maximum) on CEC C.

DDC Channel Description

VccC

Dynamic Driver (w/ Time Out)

Internal Direction Generator & Ctrl

Step-up Translator

VccA

Npass Gate

Step-down Translato

VccA

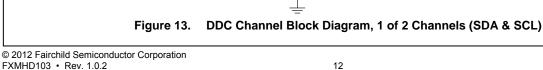
Internal Direction Generator & Ctrl

Dynamic Driver (w/ Time Out)

The HDMI specification implements the Video Electronics Standards Association (VESA) Display Data Channel (DDC) for communication between a single HDMI source and a single HDMI sink. The DDC is used by the HDMI source to read the sink's Enhanced Extended Display HDMI Identification Data (E-EDID) to discover the sink's configuration or capabilities. DDC must meet the I²C specification, version 2.1, for Standard Mode devices. Because the HDMI application is meant for high-definition Transition-Minimized Differential Signaling (TMDS) video transport across a cable, the HDMI specification requires the DDC signals (SCL & SDA) be able to drive a minimum capacitance of 800pF (source 50pF + cable assembly 700pF + sink 50pF). The I^2C specification requires a minimum of 400pF capacitance.

/ccC

C Port



A Port

Edge Rate Accelerators

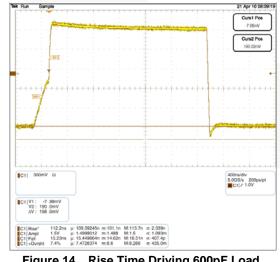
The FXMHD103 DDC channel is designed for highperformance I²C level shifting. Figure 13 shows that each bi-directional channel contains an Npassgate and two dynamic drivers. This hybrid architecture is highly beneficial in an I²C application with large capacitive loads and where auto-direction is necessary.

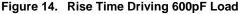
For example, during the following I²C protocol events the bus direction needs to change from "Source-to-Sink" to "Sink-to-Source" without the occurrence of an edge:

- Clock Stretching
- Slave's ACK Bit (9th bit=0) following a Master's Write Bit (8th bit=0)
- Clock Synchronization and Multi Master Arbitration

If there is an I²C translator between the source and sink in these examples, the I²C translator must change direction when both A and C ports are LOW. The Npassgate can accomplish this efficiently because, when both A and C ports are LOW, the Npassgate acts as a low resistive short between the (A and C) ports.

Due to the I^2C open-drain topology, I^2C drivers are not push/pull devices. Logic LOWs are "pulled down" (Isink), while logic HIGHs are "let go" (3-state). For example, when the source lets go of SCL (SCL always comes from the source), the rise time of SCL is largely determined by the RC time constant, where R=RPU and C=the bus capacitance. If the FXMHD103 is attached to the source [on the A port] and there is a source on the C port, the Npassgate acts as a low-resistive short between both ports until either of the port's V_{CC/2} thresholds is reached. After the RC time constant has reached the V_{CC/2} threshold of either port, the port's edge detector triggers both dynamic drivers to drive their respective ports in the LOW-to-HIGH (LH) direction, accelerating the rising edge. The resulting rise time resembles the scope shot in Figure 14. Effectively, two distinct slew rates appear in rise time. The first slew rate (slower) is the RC time constant of the bus. The second slew rate (much faster) is the dynamic driver accelerating the edge.





If both the A and C ports of the translator are HIGH, a high-impedance path exists between the A and C ports because both the Npassgates are turned off. If a source or sink device decides to pull SCL or SDA LOW, that device's driver pulls down (I_{sink}) SCL or SDA until the edge reaches the A or C port $V_{CC}/2$ threshold. When either the A or C port threshold is reached, the port's edge detector triggers both dynamic drivers to drive their respective ports in the HIGH-to-LOW (HL) direction, accelerating the falling edge.

Driving a Capacitive Load

The FXMHD103 dynamic drivers have enough current sourcing capability to drive an 800pF capacitive bus. The Figure 14 scope shot is of an FXMHD103 driving a lumped load of 600pF. Notice the (30% - 70%) rise time is only 112ns (R_{PU} =5K Ω). This is well below the maximum rise time of 1000ns in Standard Mode (100KHz) or 300ns in Fast Mode (400KHz).

Vol vs. VIL & IoL

The I^2C specification mandates a maximum V_{IL} (I_{OL} of 3mA) of $V_{CC} \ge 0.3$ for an I²C receiver and a maximum V_{OL} of 0.4V for an I²C transmitter. If there is an HDMI source on the A port of an I²C translator with a V_{CC} of 1.8V and an HDMI sink on the I²C translator C port with a V_{CC} of 5.0V, the maximum V_{IL} of the source is (1.6V x 0.3) 480mV. Meanwhile, the sink could transmit a valid logic LOW of 0.4V to the source. 80mV is not very much margin between the maximum transmitted VoL of 400mV (HDMI sink) to the maximum received V_{IL} of 480mV (HDMI source). This appears to be an oversight in the I²C specification, but there is an explanation. The I²C specification assumes transmitters and receivers share the same V_{CC}. The I²C specification does call out separate V_{OL} requirements vs. V_{CC} conditions where V_{OL1}=0.4V when V_{CC} is > 2.0V and V_{OL3}=0.2 x V_{CC}, when V_{CC} is < 2.0V. When there is V_{CC} alignment between I²C transmitters and receivers, the I²C specification provides adequate V_{IL} vs. V_{OL} margins. However, when you have a transmitter operating at 5V and a receiver operating at 1.6V through a translator or level shifter, the V_{OL} vs. V_{IL} margin gets very tight, as in the above example. Therefore, the voltage drop across the I²C translator must be as low as possible.

In general, if the I²C translator's channel resistance is too high, the voltage drop across the translator could present a VIL to a receiver greater than the receiver's maximum V_{IL} . To complicate matters, the I^2C specification states that 6mA of IoL is recommended for bus capacitances approaching 400pF in Fast Mode. More I_{OL} increases the voltage drop across the I²C translator. The I²C application benefits when I²C translators exhibit low VoL performance. Table 3 depicts the FXMHD103 targeted VoL performance vs. VIL/IOL when the direction is from C side to A side, V_{CCC} =5.0V and V_{CCA}=1.6V.

V _{IL} (mV)	I _{oL} (mA)	V _{oL} Max. (mV)	Voltage Drop Max. (mV)	Calculated Max. R_{ON} (Ω)
0	6	50	50	8.33
250	6	300	50	8.33
300	6	350	50	8.33
400	6	450	50	8.33
600	6	650	50	8.33

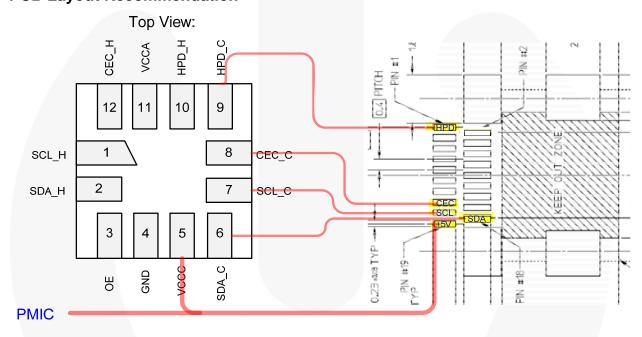
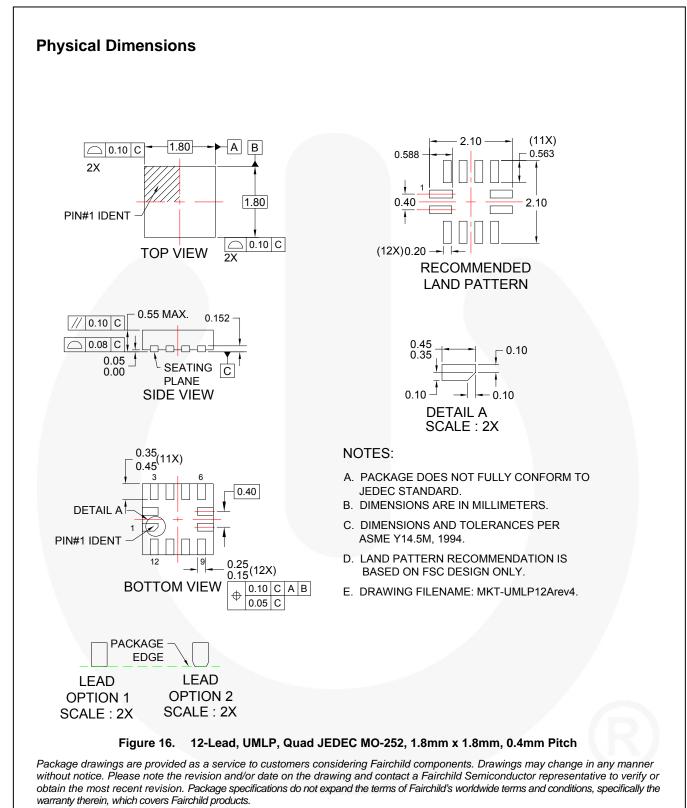


Figure 15. PCB Routing Example (Molex HDMI Type-D Connector)



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